

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S70	1530	"349".clas. and ((source drain) adj electrode) with (includ\$5) with (semiconductor silicon si)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/08/14 11:50
S71	285	"349".clas. and ((source drain) adj electrode) with (includ\$5) with (semiconductor silicon si) with transparent	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/08/14 11:50
S72	40	"349".clas. and ((source drain) adj electrode) near3 (includ\$5) with (semiconductor silicon si) with transparent	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/08/14 11:52
S73	12	"349".clas. and ((source drain) adj electrode) near3 refer\$5 with (semiconductor silicon si) with transparent	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/08/14 11:53
S74	69	"349".clas. and ((source drain) adj electrode) near3 (refer refers referring)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/08/14 12:03
S75	29	"349".clas. and ((source drain) adj electrode) with "can" with (refer refers referring includ\$5) with (transparent metal conduct\$5)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/08/14 13:28
S76	1034	"349".clas. and ((source drain) adj electrode) with (defin\$6)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/08/14 12:09
S77	874	"349".clas. and ((source drain) adj electrode) with (define defined definition)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/08/14 12:09
S78	355	"349".clas. and ((source drain) adj electrode) with (define defined definition) with (includ\$5)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/08/14 12:11
S79	10	"349".clas. and ((source drain) adj electrode) with (definition)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/08/14 13:15
S80	2	("20020075429").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2006/08/14 13:17

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S81	2	("5726461").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2006/08/14 13:17
S82	201	"349".clas. and ((source drain) adj electrode) with (includ\$5) adj10 ((semiconductor silicon) and (metal conduct\$5 transparent))	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/08/14 13:30
S83	32	"349".clas. and ((source drain) adj electrode) adj5 (includ\$5) adj10 ((semiconductor silicon) and (metal conduct\$5 transparent))	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/08/14 13:42
S84	0	"349".clas. and ((source drain) adj electrode) adj5 (refer\$3) adj10 ((semiconductor silicon) and (metal conduct\$5 transparent))	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/08/14 13:43
S85	0	"349".clas. and ((source drain) adj electrode) adj5 (pertain\$5) adj10 ((semiconductor silicon) and (metal conduct\$5 transparent))	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/08/14 13:43
S86	2	"349".clas. and ((source drain) adj electrode) adj5 (reference) adj10 ((semiconductor silicon) and (metal conduct\$5 transparent))	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/08/14 13:44
S87	0	"349".clas. and ((source drain) adj electrode) adj5 (denot\$5) adj10 ((semiconductor silicon) and (metal conduct\$5 transparent))	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/08/14 13:44
S88	1	"349".clas. and ((source drain) adj electrode) adj5 ((made make) adj up) adj10 ((semiconductor silicon) and (metal conduct\$5 transparent))	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/08/14 13:45
S89	4	"349".clas. and ((source drain) adj electrode) adj5 (compris\$5) adj10 ((semiconductor silicon si) and (metal conduct\$5 transparent ito indium))	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/08/14 13:46
S90	1	"349".clas. and ((source drain) adj electrode) adj5 (includ\$5) adj10 ((semiconductor silicon si) and (metal conduct\$5 transparent ito indium)) not S83	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/08/14 13:47
S91	1	"349".clas. and ((source drain) adj electrode) adj5 scope\$5	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/08/14 14:01
S92	2872	349/42,43.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/08/14 14:01

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S93	1995	349/149-152.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/08/14 14:01
S94	130	S92 and S93	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/08/14 15:00
S95	1	(S92 S93) and ((align\$5 orient\$5) adj (film layer)) near5 (contact\$5 touch\$5 "directly on") near5 ((source drain) adj electrode)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/08/14 14:28
S96	4	(S92 S93) and ((align\$5 orient\$5) adj (film layer)) near10 (contact\$5 touch\$5 "directly on") near10 ((source drain) adj electrode)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/08/14 14:28
S97	26	"349".clas. and ((align\$5 orient\$5) adj (film layer)) near10 (contact\$5 touch\$5 "directly on") near10 ((source drain) adj electrode)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/08/14 14:32
S98	2	("20020071065").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2006/08/14 14:33
S99	2	("20010010718").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2006/08/14 15:01
S10 0	2	("20010030718").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2006/08/14 15:01
S10 1	2	("20020071065").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2006/08/15 07:23
S10 2	2	("20010035527").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2006/08/15 07:40
S10 3	1	349/187.ccls. and (ash\$5 (dry adj strip\$5)) with (dry adj etch\$5) with (chamber\$5)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/08/15 07:52
S10 4	8	349/187.ccls. and (ash\$5 (dry adj strip\$5)) with (dry adj etch\$5)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/08/15 07:56

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S10 5	13	349/187.ccls. and (ash\$5 (dry adj strip\$5)) same (dry adj etch\$5)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/08/15 08:00
S10 6	525	(liquid adj crystal) and (ash\$5 (dry adj strip\$5)) with (dry adj etch\$5)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/08/15 08:01
S10 7	31	(liquid adj crystal) and (ash\$5 (dry adj strip\$5)) with (dry adj etch\$5) with chamber	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/08/15 08:46
S10 8	2	("20020071065").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2006/08/15 08:46
S10 9	2	("20010030718").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2006/08/15 08:46